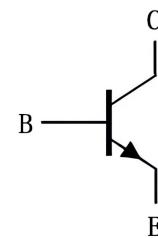


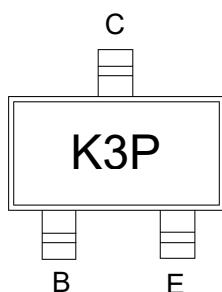
Features

- Epitaxial planar die construction
- Complementary PNP Type available(MMST2907A)



SOT-323 top view

Schematic diagram



Marking and pin assignment



Halogen-Free

Maximum Ratings (Ta=25°C unless otherwise noted)

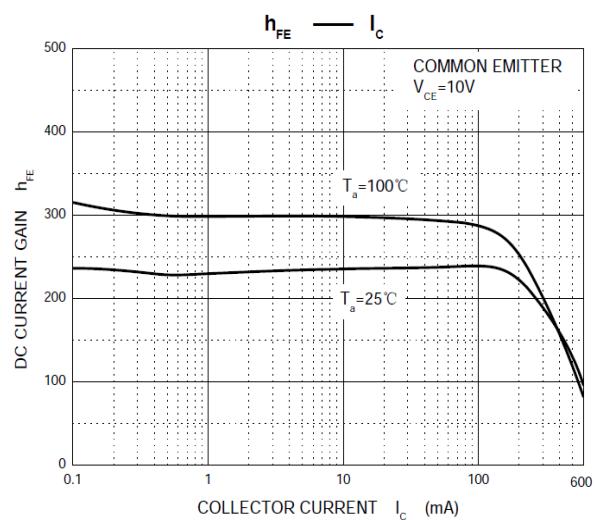
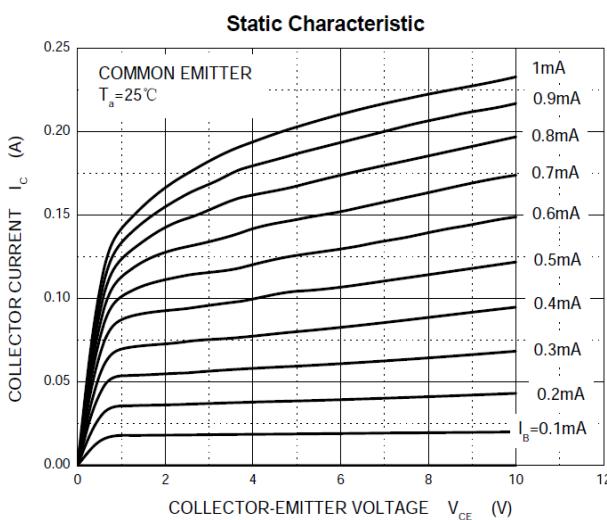
Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	75	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	600	mA
P _C	Collector Power Dissipation	200	mW
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

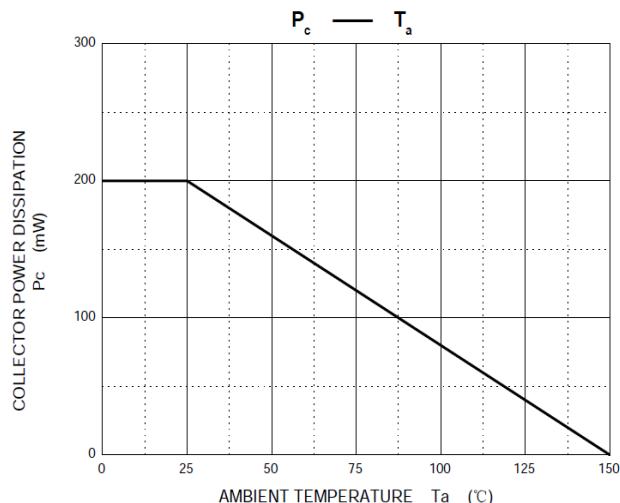
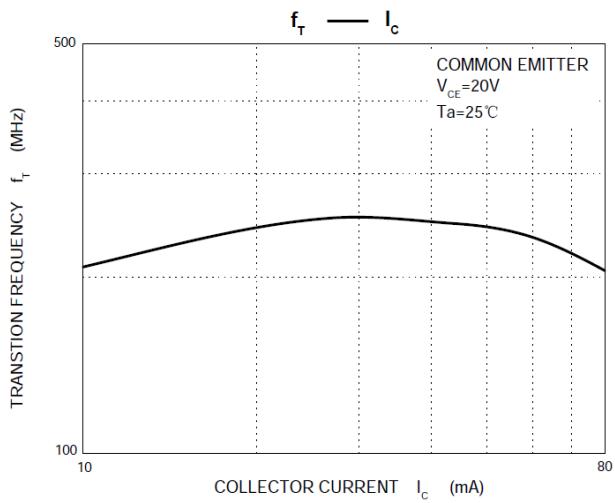
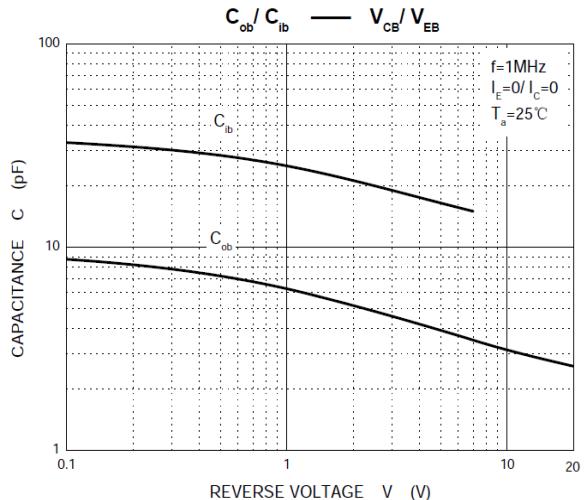
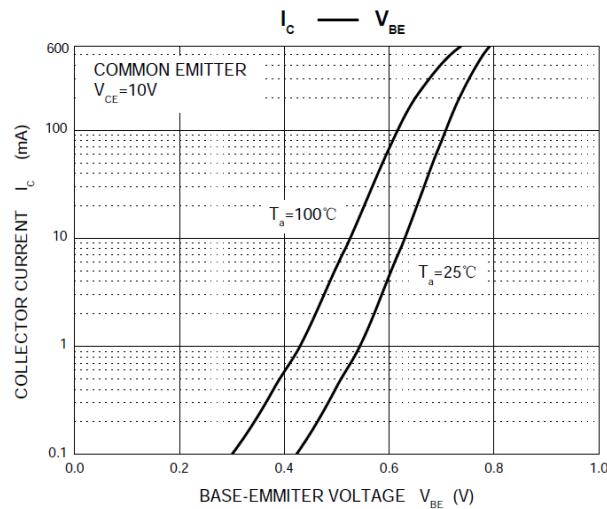
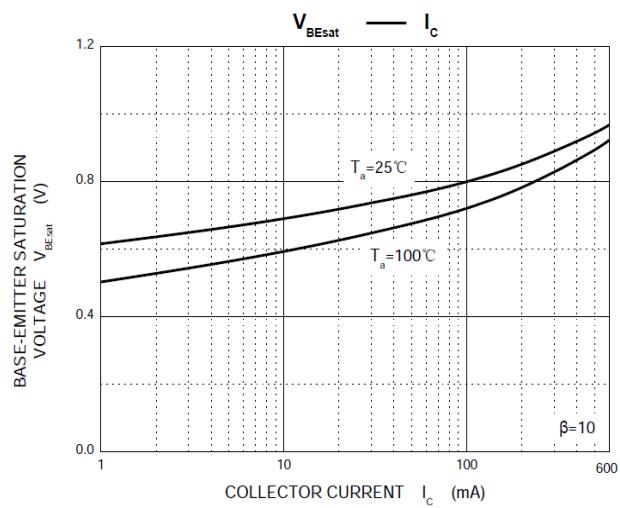
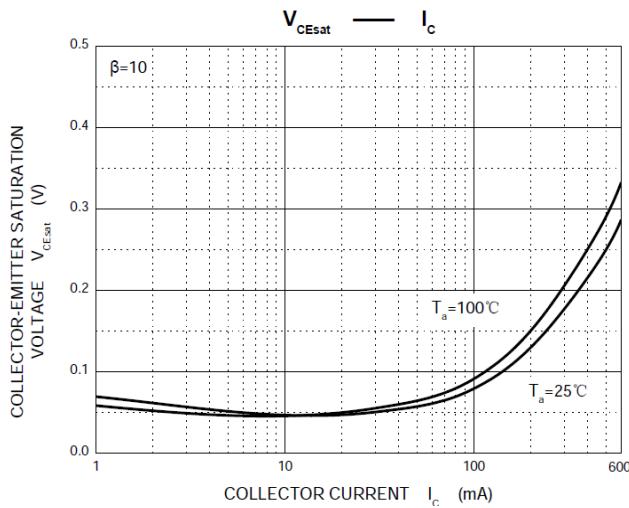
Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MMST2222A	SOT-323	K3P	3,000	45,000	180,000	7"reel

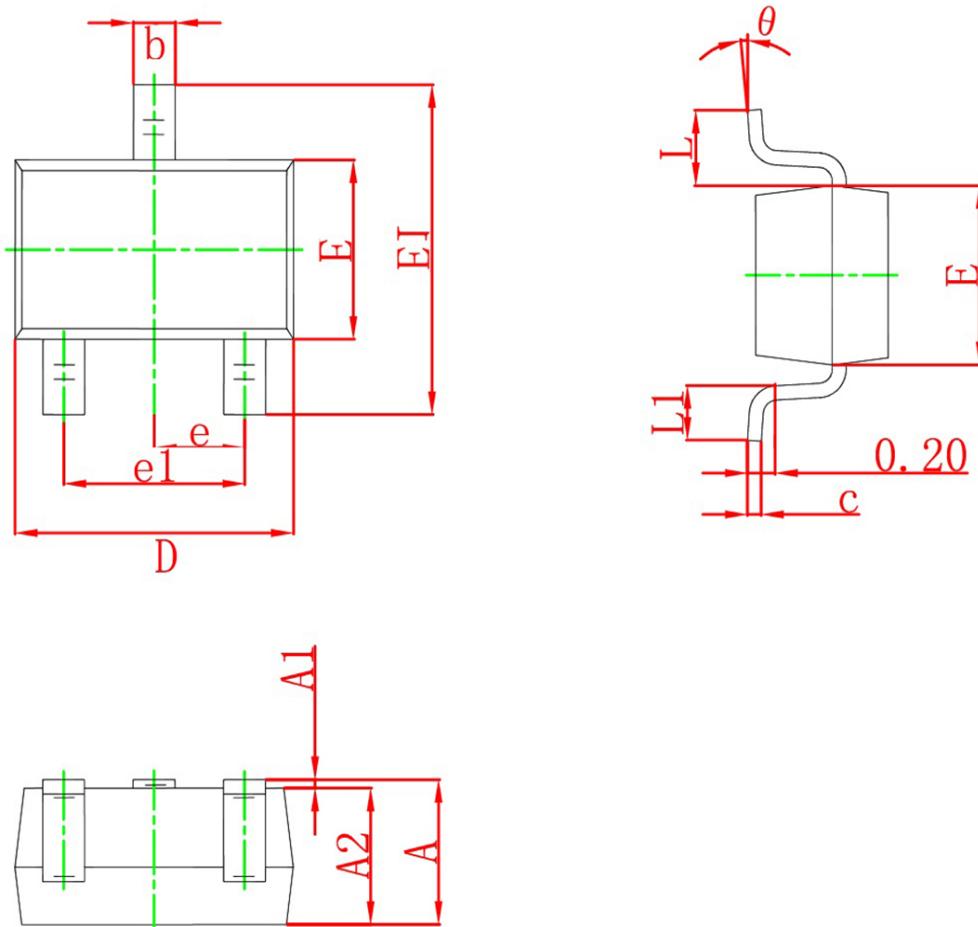
Electrical Characteristics (Ta=25°C unless otherwise specified)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =10μA, I _E =0	75	--	--	V
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =10mA, I _B =0	40	--	--	V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =10μA, I _C =0	6	--	--	V
I _{CBO}	Collector cut-off current	V _{CB} =70V, I _E =0	--	--	100	nA
I _{EBO}	Emitter cut-off current	V _{EB} =3V, I _C =0	--	--	100	nA
I _{CEO}	Collector cut-off current	V _{CE} =35V, I _B =0	--	--	100	nA
H _{FE1}	DC current gain	V _{CE} =10V, I _C =0.1mA	35	--	--	
H _{FE2}		V _{CE} =10V, I _C = 1mA	50			
H _{FE3}		V _{CE} =10V, I _C = 10mA	75			
H _{FE4}		V _{CE} =10V, I _C = 150mA	100			
H _{FE5}		V _{CE} =10V, I _C = 500mA	40			
H _{FE6}		V _{CE} =1V, I _C = 150mA	35	--	--	
V _{CE(sat)}	Collector-emitter saturation voltage	I _C =500mA, I _B =50mA	--	--	1	V
		I _C =150mA, I _B =15mA	--	--	0.3	V
V _{BE(sat)}	Base-emitter saturation voltage	I _C =500mA, I _B =50mA			2.0	V
		I _C =150mA, I _B =15mA	--	--	1.2	V
f _T	Transition frequency	V _{CE} =20V, I _C =20mA, f=100MHz	300	--	--	MHz
C _{ob}	Collector output capacitance	V _{CB} =10V, I _E =0, f=1MHz	--	--	8	pF
t _d	Delay time	V _{CC} =30V, V _{BE(off)} =-0.5V	--	--	10	ns
t _r	Rise time	I _C =150mA, I _{B1} = 15mA	--	--	25	ns
t _s	Storage time	V _{CC} =30V, I _C =150mA	--	--	225	ns
t _f	Fall time	I _{B1} =I _{B2} =15mA	--	--	60	ns

Typical Characteristics




SOT-323 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°